

Vishay Siliconix

0.4 Ω , Low Resistance and Capacitance, Dual DPDT / Quad SPDT Analog Switch

DESCRIPTION

The DG2523 and DG2524 are four-channel single-pole double-throw (SPDT) analog switches. The DG2523 has two control inputs that each controls a pair of single-pole double-throw (SPDT). It is also known as a two-channel double-pole double-throw (DPDT) configuration. The DG2524 has an $\overline{\text{EN}}$ pin to enable the device when the logic is low.

The parts are designed to operate from 1.8 V to 5.5 V single power rail. All switches conduct equally well in both directions, offering rail to rail signal witching and can be used both as multiplexers as well as de-multiplexers. The parts feature low control logic threshold. Break-before-make switching is guaranteed.

The DG2523 and DG2524 exhibit low parasitic capacitance, low leakage, and highly matched low and flat switch resistance over the full signal range characters that are important for precision analog designs.

The high bandwidth and excellent total harmonic distortion (THD) performance make them ideal for both analog and digital signal switching in space constrain applications requiring high performance and efficient use of board space.

The DG2523 and DG2524 come in Pb-free QFN-16 package of 3 mm x 3 mm.

BENEFITS

- · Low and flat resistance
- · Excellent total harmonic distortion
- · Low parasitic capacitance
- Low voltage control interface

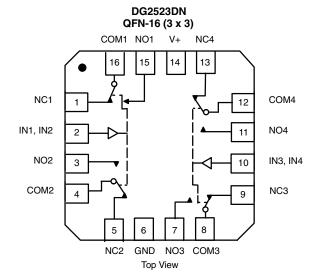
FEATURES

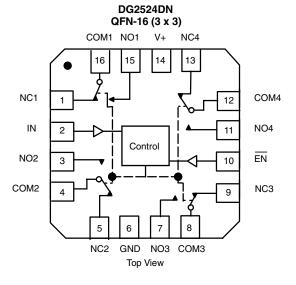
- 1.8 V to 5.5 V single supply operation
- Low resistance: 0.4 Ω / typ. at 2.7 V
- Highly flat and matched Ron
- Low parasitic capacitance,
 C_{on} = 26 pF, C_{off} = 14.5 pF
- Typical switch off leakage of 40 pA
- High bandwidth: 310 MHz
- Guaranteed logic high 1.2 V, logic low 0.3 V
- · Break before make switching
- Signal swing over V+ capable
- Power down protection
- Latch up current: 300 mA (JESD78)
- ESD/HBM: > 6 kV
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Automatic test equipment
- Data acquisition systems
- · Meters and instruments
- Medical and healthcare systems
- · Communication systems
- · Audio and video signal routing
- Battery powered systems
- Computer peripherals
- Data storage
- Relay replacement

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION







Vishay Siliconix

TRUTH TABLE DG2523							
INx	NC1, 2, 3, and 4	NO1, 2, 3, and 4					
0	On	Off					
1	Off	On					

TRUTH TABLE DG2524								
EN	LOGIC IN NC1, 2, 3, and 4 NO1, 2, 3, and							
1	х	Off	Off					
0	0	On	Off					
0	1	Off	On					

ORDERING INFORMATION								
TEMPERATURE RANGE	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY					
-40 °C to +85 °C lead (Pb)-free	QFN-16 (3 mm x 3 mm)	DG2523DN-T1-GE4	Tape and reel, 2500 units					
	QFN-10 (3 IIIII X 3 IIIII)	DG2524DN-T1-GE4	rape and reer, 2500 units					

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)								
PARAMETER		SYMBOL	LIMIT	UNIT				
Reference to GND	V+		-0.3 to +6	V				
	IN, COM, NC, NO a		-0.3 to (V+ + 0.3)	v				
Current (any terminal except NO, NC, or	COM)		30					
Continuous current (NO, NC, or COM)		± 300	mA					
Peak current (pulsed at 1 ms, 10 % duty		± 500						
Storage temperature (D suffix)		-65 to +150	°C					
Package solder reflow conditions ^d	QFN-16		250					
Power dissipation (packages) ^b	QFN-16 °		1385	mW				

Notes

- a. Signals on NC, NO, or COM, or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 17.3 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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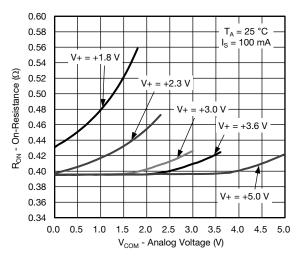
		TEST CONDITIONS		LIMITS			
PARAMETER	SYMBOL	unless otherwise specified	TEMP.a		°C to +8		UNIT
		$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 V \text{ or } 1.4 V ^{\circ}$		MIN. b	TYP. c	MAX. b	
Analog Switch	ı			T	T	1	
Analog signal range d	V_{NO}, V_{NC}, V_{COM}		Full	0	-	V+	V
On-resistance	R _{ON}	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to } 2.7 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$		-	0.40	0.55	
	. ion		Full	-	-	0.65	Ω
R _{ON} flatness ^d	R _{ON} flatness	$V+ = 2.7 V, V_{COM} = 0 \text{ to } V+,$	Full		0.03	0.08	
R _{ON} match ^d	ΔR_{ON}	I_{NO} , $I_{NC} = 100 \text{ mA}$	Room		0.05	-	
	I _{NO(off)} ,		Room	-1	0.04	1	
Switch off leakage current	I _{NC(off)}	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = 0.5 \text{ V} / 4 \text{ V},$	Full	-5	-	5	
Switch on leakage current		$V_{COM} = 4 \text{ V} / 0.5 \text{ V}$	Room	-1	0.17	1	nA
	I _{COM(off)}		Full	-5	-	5	ПА
Channel-on leakage		V. FEVV V V OFV/4V	Room	-1	0.17	1	
current	I _{COM(on)}	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.5 \text{ V} / 4 \text{ V}$	Full	-5	-	5	
Digital Control							
Input high voltage	V _{INH}		- "	1.2	-	-	.,
Input low voltage	V _{INL}		Full	-	-	0.3	V
Input capacitance	C _{IN}		Full	-	5	-	pF
Input current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	-1	-	1	μΑ
Dynamic Characteristics				L	L		
			Room	-	38	60	μs
Turn-on time	t _{ON}		Full	-	-	70	
	t _{OFF}	V_{NO} or $V_{NC} = 1.5 \text{ V}$, $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$	Room	_	0.43	1	
Turn-off time			Full	-	-	3	
Break-before-make time	t _d		Full	1	_	-	
Charge injection ^d	Q _{INJ}	$C_L = 1 \text{ nF}, V_{GEN} = 1.5 \text{ V}, R_{GEN} = 0 \Omega$	Room	-	-19	-	рС
-3 dB bandwidth	BW	$R_L = 50 \Omega$, $C_L = 5 pF$	Room	-	310	-	MHz
		$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 kHz$		-	-82	-	
Off-isolation d	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$		-	-55	-	
		$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 kHz$	D	-	-89	-	-ID
Crosstalk d, f	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room	-	-61	-	dB
Total harmonic distortion plus noise	THD + N	2.5 V, signal peak to peak voltage $R_L = 32 \Omega, f = 1 \text{ kHz}$		-	-100	-	
•	C _{NO(off)}	- ·	Room	-	14.5	-	pF
NO, NC off capacitance d	C _{NC(off)}			_	14.5	-	
	C _{NO(on)}	f = 1 MHz		-	26	-	
Channel-on capacitance d	C _{NC(on)}			-	26	-	
Power Supply	110(011)					<u> </u>	
Power supply range	V+			1.8	_	5.5	V
Power supply current	I+	V _{IN} = 0 or V+	Full	-	29	60	μA
. S. or supply surrout		1 IIV = 2 OL 1				- 50	۲, ۲

Notes

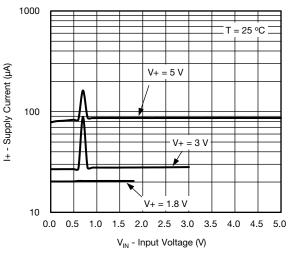
- a. Room = 25 $^{\circ}$ C, full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Crosstalk measured between channels.



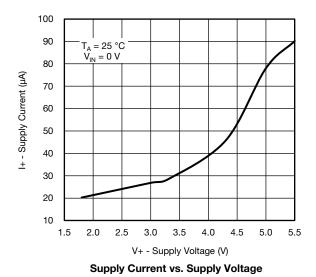
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



R_{ON} vs. V_{COM} and Supply Voltage

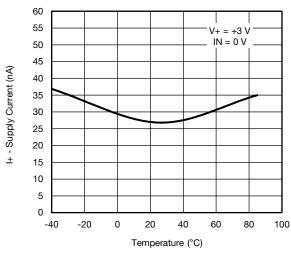


Supply Current vs. Input Voltage

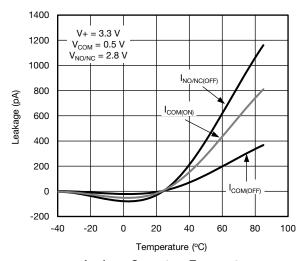


0.56 0.54 V+ = +3.0 VI_S = 100 mA 0.52 +85 °C 0.50 0.48 0.46 On-Resistance 0.44 +25 °C 0.42 0.40 0.38 -40 °C 0.36 0.34 0.32 0.30 0.28 0.26 0.24 0.0 0.5 1.0 1.5 2.0 2.5 3.0 V_{COM} - Analog Voltage (V)

R_{ON} vs. Analog Voltage and Temperature



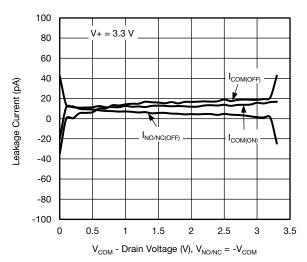
Supply Current vs. Temperature



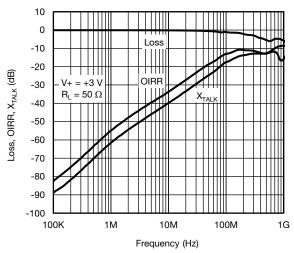
Leakage Current vs. Temperature



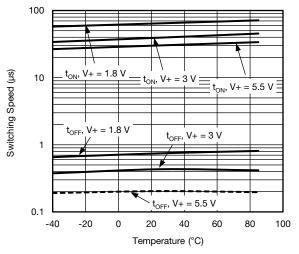
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



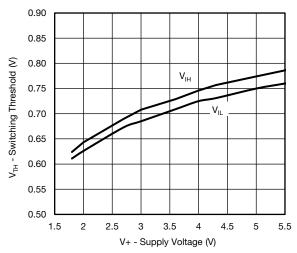
Leakage Current vs. Drain Voltage



Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Switching Time vs. Temperature

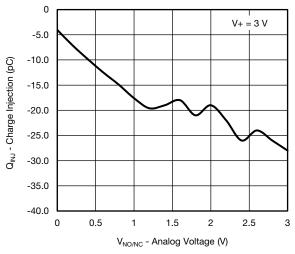


Switching Threshold vs. Supply Voltage

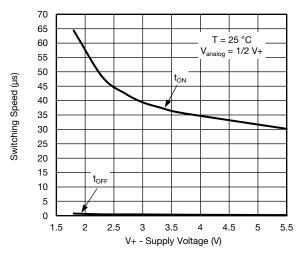
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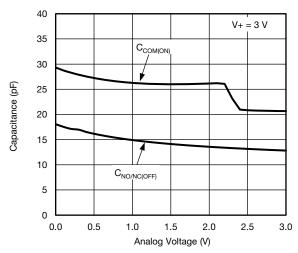
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Charge Injection vs. Analog Voltage



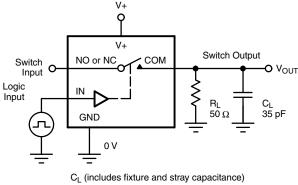
Switching Time vs. Supply Voltage



Capacitance vs. Analog Voltage



TEST CIRCUITS



 V_{INH} t_r < 5 ns Logic 50 % $t_f < 5 \text{ ns}$ Input V_{INL} 0.9 x V_{OUT} Switch Output 0 V t_{ON}

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

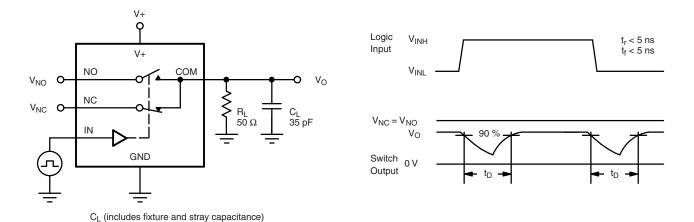


Fig. 2 - Break-Before-Make Interval

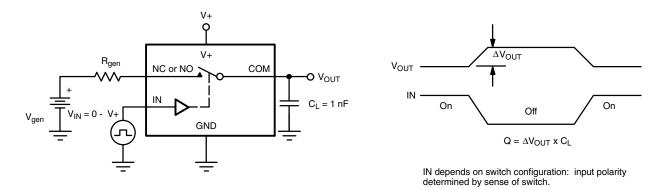


Fig. 3 - Charge Injection



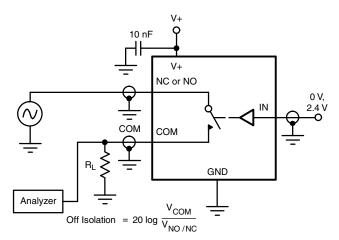


Fig. 4 - Off-Isolation

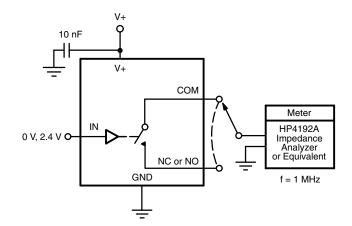


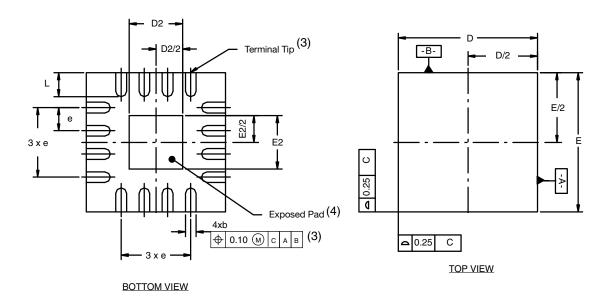
Fig. 5 - Channel Off / On Capacitance

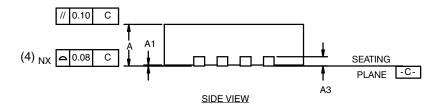
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QFN-16 Lead (3 x 3)





Notes

- (1) All dimensions are in millimeters.
- (2) N is the total number of terminals.
- (3) Dimension b applies to metallized terminal and is measured between 0.25 and 0.30 mm from terminal tip.
- (4) Coplanarity applies to the exposed heat sink slug as well as the terminal.
- (5) The pin #1 identifier may be either a mold or marked feature, it must be located within the zone indicated.

	VARIATION 1						VARIATION 2					
DIM.	MILLIMETERS		INCHES		MILLIMETERS			INCHES				
	MIN.	NOM	MAX.	MIN.	NOM	MAX.	MIN.	NOM	MAX.	MIN.	NOM	MAX.
А	0.80	0.90	1.00	0.031	0.035	0.039	0.80	0.90	1.00	0.031	0.035	0.039
b	0.18	0.23	0.30	0.007	0.009	0.012	0.18	0.25	0.30	0.007	0.010	0.012
D	2.90	3.00	3.10	0.114	0.118	0.122	2.90	3.00	3.10	0.114	0.118	0.122
D2	1.00	1.15	1.25	0.039	0.045	0.049	1.50	1.70	1.80	0.059	0.067	0.071
E	2.90	3.00	3.10	0.114	0.118	0.122	2.90	3.00	3.10	0.114	0.118	0.122
E2	1.00	1.15	1.25	0.039	0.045	0.049	1.50	1.70	1.80	0.059	0.067	0.071
е		0.50 BSC		0.020 BSC		0.50 BSC		0.020 BSC		;		
L	0.30	0.40	0.50	0.012	0.016	0.020	0.30	0.40	0.50	0.012	0.016	0.020

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DWG: 5899



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